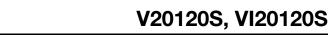
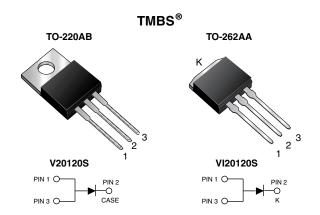
**New Product** 



Vishay General Semiconductor

# High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.50$  V at  $I_F = 5$  A



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	20 A				
V <sub>RRM</sub>	120 V				
I <sub>FSM</sub>	200 A				
$V_F$ at $I_F = 20$ A	0.73 V				
T <sub>J</sub> max.	150 °C				

## **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per FREE JESD 22-B106
- AEC-Q101 qualified
- · Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

## **TYPICAL APPLICATIONS**

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: TO-220AB and TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

Base P/NHM3 - halogen-free, RoHS compliant, and AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD class 2 whisker test

#### Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	V20120S VI20120S		UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	120		V		
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	20		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	200		А		
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 40 to + 150		°C		

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BoHS COMPLIANT HALOGEN



# V20120S, VI20120S

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.57	-	V	
	I <sub>F</sub> = 10 A			0.71	-		
	I <sub>F</sub> = 20 A			0.99	1.12		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.50	-		
	I <sub>F</sub> = 10 A			0.61	-		
	I <sub>F</sub> = 20 A			0.73	0.81		
Reverse current	V <sub>R</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	10	-	μA	
		T <sub>A</sub> = 125 °C		6	-	mA	
	V = 120 V	T <sub>A</sub> = 25 °C		-	300	μA	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 125 °C		14	30	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	BOL V20120S VI20120S		UNIT	
Typical thermal resistance	$R_{ extsf{ heta}JC}$	2.0		°C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	V20120S-M3/4W	1.88	4W	50/tube	Tube	
TO-262AA	VI20120S-M3/4W	1.45	4W	50/tube	Tube	
TO-220AB	V20120SHM3/4W (1)	1.88	4W	50/tube	Tube	
TO-262AA	VI20120SHM3/4W <sup>(1)</sup>	1.45	4W	50/tube	Tube	

Note

(1) AEC-Q101 qualified

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## V20120S, VI20120S

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## **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

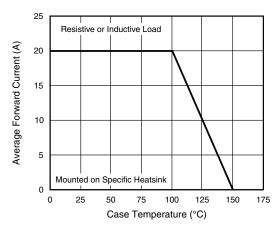


Fig. 1 - Maximum Forward Current Derating Curve

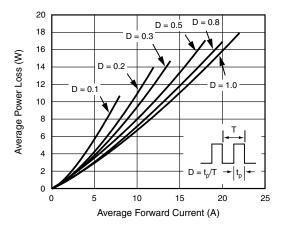


Fig. 2 - Forward Power Dissipation Characteristics

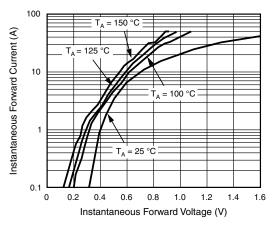


Fig. 3 - Typical Instantaneous Forward Characteristics

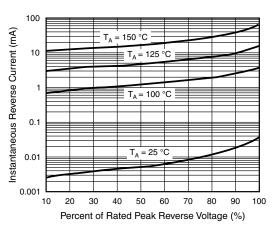


Fig. 4 - Typical Reverse Characteristics

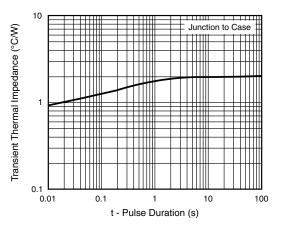
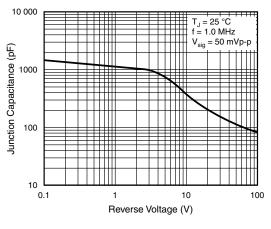


Fig. 5 - Typical Transient Thermal Impedance





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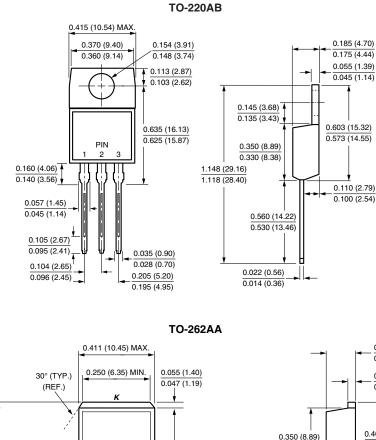
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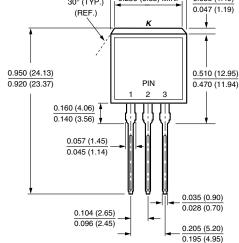
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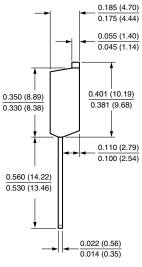
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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)







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